## FAIRCHILD

SEMICONDUCTOR®

## BD433/435/437

# Medium Power Linear and Switching Applications

• Complement to BD434, BD436 and BD438 respectively



## **NPN Epitaxial Silicon Transistor**

Absolute Maximum Ratings  $T_{C}$ =25°C unless otherwise noted

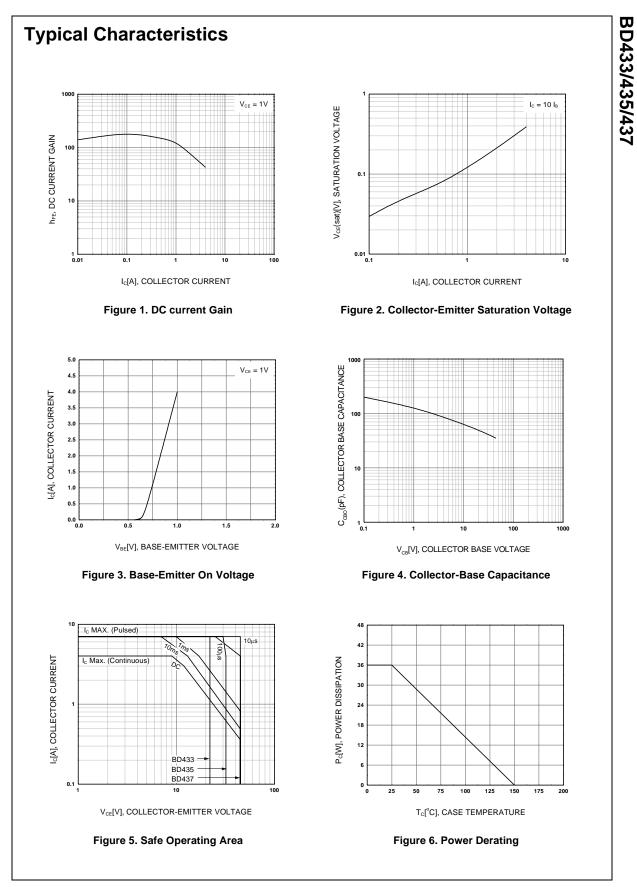
Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: BD433	22	V
	: BD435	32	V
	: BD437	45	V
/ <sub>CES</sub>	Collector-Emitter Voltage		
020	: BD433	22	V
	: BD435	32	V
	: BD437	45	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
020	: BD433	22	V
	: BD435	32	V
	: BD437	45	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
С	Collector Current (DC)	4	А
СР	*Collector Current (Pulse)	7	А
I <sub>B</sub>	Base Current	1	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	36	W
Т <sub>Ј</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
<sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage					
020( )	: BD433	$I_{C} = 100 \text{mA}, I_{B} = 0$	22			V
	: BD435	-	32			V
	: BD437		45			V
Сво	Collector Cut-off Current					
	: BD433	$V_{CB} = 22V, I_E = 0$			100	μΑ
	: BD435	$V_{CB} = 32V, I_{E} = 0$			100	μΑ
	: BD437	$V_{CB} = 45V, I_E = 0$			100	μΑ
I <sub>CEO</sub>	Collector Cut-off Current					
	: BD433	$V_{CE} = 22V, V_{BE} = 0$			100	μΑ
	: BD435	$V_{CE} = 32V, V_{BE} = 0$			100	μΑ
	: BD437	$V_{CE} = 45V, V_{BE} = 0$			100	μΑ
BO	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			1	mA
FE	* DC Current Gain					
L	: BD433/435	$V_{CE} = 5V, I_{C} = 10mA$	40	130		
	: BD437	GE / C	30	130		
	: ALL DEVICE	$V_{CE} = 1V, I_{C} = 500 \text{mA}$	85	140		
	: BD433/435	$V_{CE} = 1V, I_{C} = 2A$	50			
	: BD437	02 0	40			
<sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage					
	: BD433	$I_{\rm C} = 2A, I_{\rm B} = 0.2A$		0.2	0.5	V
	: BD435			0.2	0.5	V
	: BD437			0.2	0.6	V
<sub>BE</sub> (on)	* Base-Emitter ON Voltage					
	: BD433	$V_{CE} = 1V, I_{C} = 2A$			1.1	V
	: BD435				1.1	V
	: BD437				1.2	V
	Current Gain Bandwidth Product	$V_{CE} = 1V, I_{C} = 250 \text{mA}$	3			MHz
	00µs, duty Cycle=1.5% Pulsed				I	

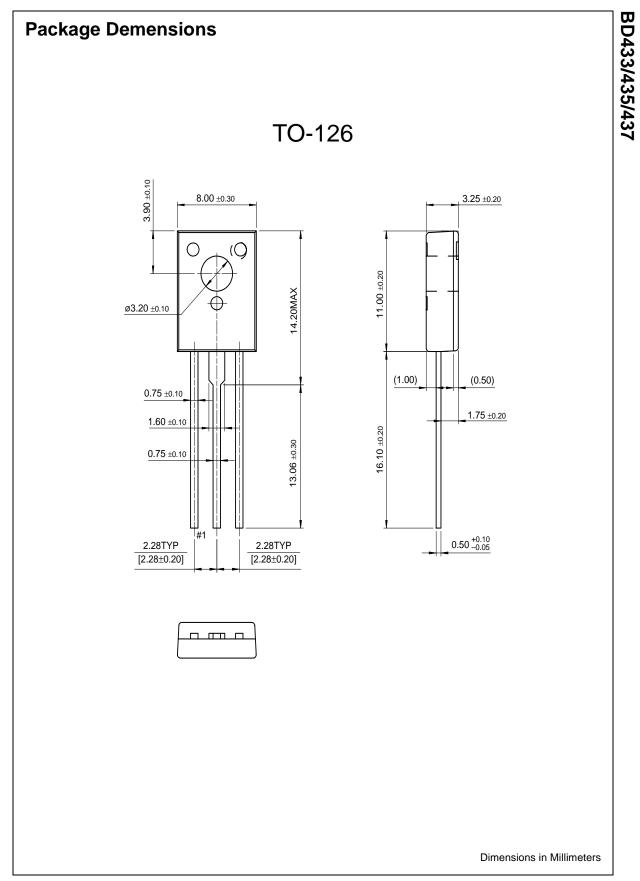
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Rev. A1, June 2001



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